

EXAMINATION IN
TSEK03
RADIO FREQUENCY INTEGRATED
CIRCUITS

Date: 2019-01-07
Time: 14-18
Location: TER2
Tools: Calculator, Dictionary
Teachers: Ted Johansson (070-6270237)
Oscar Morales (070-4023671)

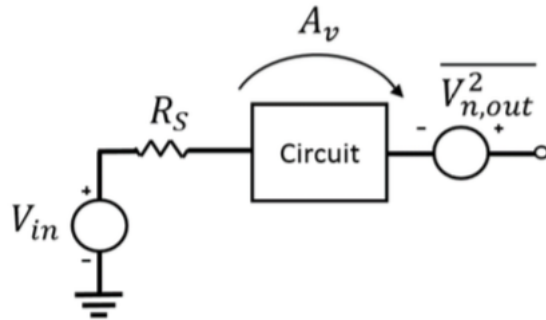
12 points are required to pass.
(12-15: 3, 16-19: 4, 20-24: 5)

Please start each new problem at the top of a page!
Only use one side of each paper!

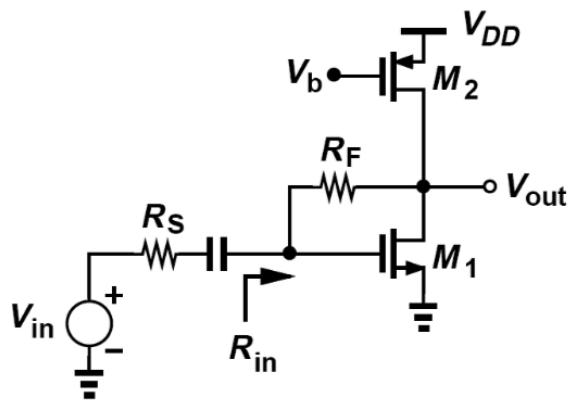
1. A circuit exhibits a noise figure of 3 dB.

- What percentage of the output noise power is due to the source resistance, R_S ? (3 p)
- Repeat the problem for $NF = 1$ dB. (1 p)

Use the simplified circuit model shown below.

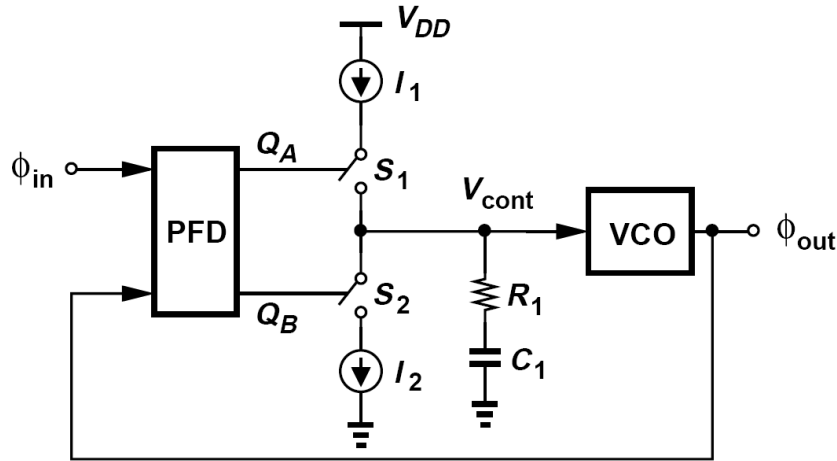


2. A common-source low noise amplifier (LNA) with feedback is shown below. R_S is the input source resistance. Assume that the transistors are long-channel devices.



- Determine the input impedance (R_{in}) of the LNA. (1 p)
- Calculate the voltage gain of the LNA (i.e., V_{out}/V_{in}) after matching if $R_F = 25 R_S$. (2 p)
- Derive an expression for the output noise of the LNA contributed by R_S after matching if $R_F = 25 R_S$. (2 p)

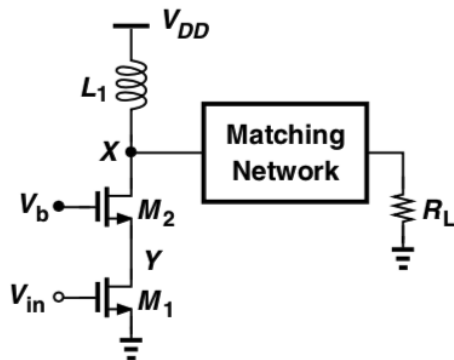
5. Derive an expression for the closed-loop phase transfer function, $H(s) = \Phi_{out}(s)/\Phi_{in}(s)$, of the CP-PLL shown below. The transfer function of the VCO is K_{VCO}/s and the transfer function of the PFD/CP is $I_0/(2\pi)$ (I_0 is the charge pump current). (4 p)



6. A cascode power amplifier is shown below.

24 dBm average output power is to be delivered to the load for an LTE up-link signal (terminal to basestation) with a Peak-to-Average-Power Ratio (PAPR) of 5 dB (peak power is 5 dB higher than the average power). The matching network has an additional loss of 1.5 dB.

- What is the required peak power in Watts to be delivered by the power amplifier? (1 p)
- What should be the load at X (looking into the Matching network) to have the PA deliver this peak power into the 50Ω load using $V_{DD} = 1.8 \text{ V}$. (2 p)
- But wait... why are we using a cascode PA, why not just single transistor (M_1) in the amplifier? (1 p)



7. Please provide short answers (no or very short motivations are needed) to the following questions:

a) For RF-circuits, a design aspect is associated with the names Stern or Rollett. What design aspect? (0.5 p)

b) If changing the circuit topology from a single-balanced to a double-balanced mixer, what happens with the conversion gain? (0.5 p)

c) Can the fringe (grid) capacitor used in advanced CMOS processing be used as a varactor? (0.5 p)

d) Circuit types/names like Clapp, Colpitt, and Hartley are associated with a certain type of radio building blocks. What type? (0.5 p)